Complementary Silicon Power Transistors

- . . . designed for general-purpose switching and amplifier applications.
- DC Current Gain $h_{FE} = 20-70 @ I_C = 4.0 Adc$
- Collector–Emitter Saturation Voltage VCE(sat) = 1.1 Vdc (Max) @ IC = 4.0 Adc
- Excellent Safe Operating Area

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCEO	60	Vdc
Collector–Emitter Voltage	VCER	70	Vdc
Collector-Base Voltage	V _{CB}	100	Vdc
Emitter-Base Voltage	V _{EB}	7.0	Vdc
Collector Current — Continuous	IC	15	Adc
Base Current	lΒ	7.0	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	90 0.72	Watts W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.39	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	35.7	°C/W

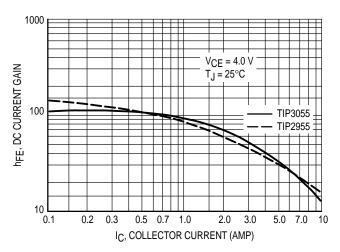
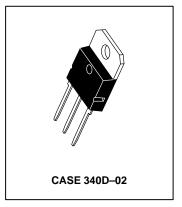


Figure 1. DC Current Gain

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15 AMPERE
POWER TRANSISTORS
COMPLEMENTARY
SILICON
60 VOLTS
90 WATTS



TIP3055 TIP2955

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Symbol	Min	Max	Unit
		•	
VCEO(sus)	60	_	Vdc
ICER	_	1.0	mAdc
ICEO	_	0.7	mAdc
ICEV	_	5.0	mAdc
I _{EBO}	_	5.0	mAdc
			•
hFE	20 5.0	70 —	_
VCE(sat)	_	1.1 3.0	Vdc
V _{BE} (on)	_	1.8	Vdc
		•	•
l _{s/b}	3.0	_	Adc
		•	
fT	2.5	_	MHz
h _{fe}	15		kHz
	VCEO(sus) ICER ICEO ICEV IEBO VCE(sat) VBE(on) IT	VCEO(sus) 60	VCEO(sus) 60 — ICER — 1.0 ICEO — 0.7 ICEV — 5.0 IEBO — 5.0 VCE(sat) — 1.1 — 3.0 — VBE(on) — 1.8

⁽¹⁾ Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

NOTE: For additional design curves, refer to electrical characteristics curves of 2N3055.

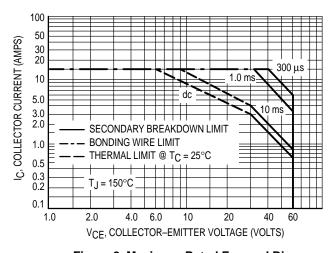
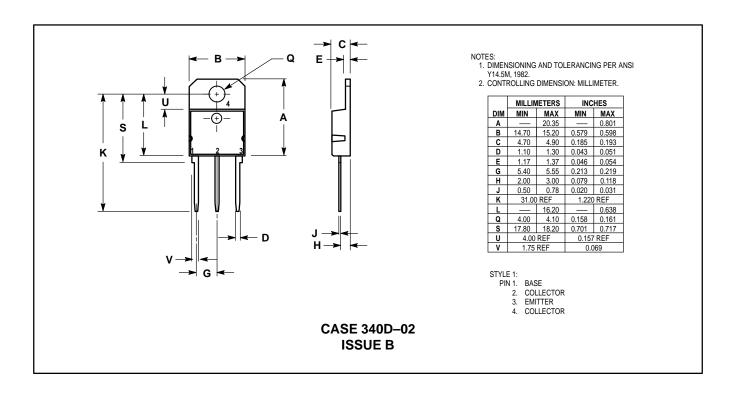


Figure 2. Maximum Rated Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate IC – VCE limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 2 is based on $T_C = 25^{\circ}C$; $T_{J(pk)}$ is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated for temperature.

PACKAGE DIMENSIONS



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How to reach us:

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036. 1–800–441–2447 or 602–303–5454

MFAX: RMFAX0@email.sps.mot.com – TOUCHTONE 602–244–6609 INTERNET: http://Design-NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, 6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 03–81–3521–8315

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298



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